



T2650NGF

主要参数 MAIN CHARACTERISTICS

$I_{T(RMS)}$	26A
V_{DRM}	800V
I_{GT}	50mA

用途

- 交流开关
- 相位控制

APPLICATIONS

- AC switching
- Phase control

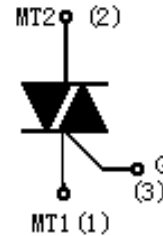
产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 三象限可控硅，触发电流的一致性好
- 环保 RoHS 产品

FEATURES

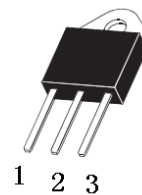
- Glass-passivated mesa chip for reliability and uniform
- Uniform gate trigger currents in three quadrants
- RoHS products

封装 Package



序号 Pin	引线名称 Description
1	主电极 1 MT1
2	主电极 2 MT2
3	门极 G

TOP3 (Insulated)



订货信息 ORDER MESSAGES

订货型号 Order codes				印 记 Marking	封 装 Package
有卤-条管	无卤-条管	有卤-编带	无卤-编带		
Halogen-Tube	halogen-Free-Tube	Halogen-Reel	Halogen-Free-Reel		
T2650NGF-GF-B	N/A	N/A	N/A	T2650NGF	TOP3

概述 GENERAL DESCRIPTION

T2650NGF是玻璃钝化芯片结构的三象限双向晶闸管，产品在第四象限不可触发，具有较高的使用可靠性。可适用于容易出现较高dV/dt或dI/dt的交流全波控制线路中，特别推荐应用与电感性负载控制（如电机控制线路）。器件封装形式为TOP3（引线与散热片绝缘）。

T2650NGF are Glass passivated three quadrant triacs, designed for high performance full-wave ac control applications where high static and dynamic dV/dt and high dI/dt can occur. They are specially recommended for use on inductive loads such as motor control circuits. Available package is TOP3(internally isolated).



绝对最大额定值 ABSOLUTE RATINGS ($T_c=25^\circ\text{C}$)

项 目 Parameter	符 号 Symbol	试 验 条 件 Condition	数 值 Value	单 位 Unit
重复峰值断态电压 Repetitive peak off-state voltage	V_{DRM}		± 800	V
通态方均根电流 On-state RMS current	$I_{\text{T(RMS)}}$	full sine wave,	26	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current	I_{TSM}	full sine wave ,t=20ms	260	A
		full sine wave ,t=16.7ms	250	A
		I^2t	t=10ms	340
通态电流临界上升率 Repetitive rate of rise of on-state current after triggering	dI/dt	$I_{\text{TM}}=30\text{A}$, $I_{\text{G}}=0.2\text{A}$, $dI_{\text{G}}/dt=0.2\text{A}/\mu\text{s}$	50	$\text{A}/\mu\text{s}$
峰值门极电流 Peak gate current	I_{GM}		4	A
峰值门极电压 Peak gate voltage	V_{GM}		5	V
峰值门极功率 Peak gate power	P_{GM}		5	W
平均门极功率 Average gate power	$P_{\text{G(AV)}}$	over any 20ms period	1.0	W
存储温度 Storage temperature	T_{stg}		-40~150	$^\circ\text{C}$
操作结温 Operation junction temperature	T_{VJ}		125	$^\circ\text{C}$



电特性 ELECTRICAL CHARACTERISTIC (T_C=25°C)

项 目 Parameter	符 号 Symbol	测 试 条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit	
峰值重复断态电流 Peak Repetitive Blocking Current	I _{DRM}	V _{DM} =V _{DRM} , T _j =25°C, gate open	-	-	10	μ A	
		V _{DM} =V _{DRM} , T _j =125°C, gate open	-	-	3.0	mA	
峰值通态电压 Peak on-state voltage	V _{TM}	I _{TM} =56A	-	-	1.6	V	
门极触发电流 Gate trigger current	I _{GT}	V _{DM} =12V, R _L =100 Ω	MT1(-),MT2(+),G(+)	5	-	50	mA
			MT1(-),MT2(+),G(-)	5	-	50	mA
			MT1(+),MT2(-),G(-)	5	-	50	mA
门极触发电压 Gate trigger voltage	V _{GT}	V _{DM} =12V, R _L =100 Ω	MT1(-),MT2(+),G(+)	-	0.7	1.5	V
			MT1(-),MT2(+),G(-)	-	0.7	1.5	V
			MT1(+),MT2(-),G(-)	-	0.7	1.5	V
维持电流 Holding current	I _H	V _{DM} =12V, I _{GT} =0.1A	-	-	80	mA	
擎住电流 Latching current	I _L	V _{DM} =12V, I _{GT} =0.1A	MT1(-),MT2(+),G(+)	-	-	70	mA
			MT1(-),MT2(+),G(-)	-	-	160	mA
			MT1(+),MT2(-),G(-)	-	-	70	mA
断态临界电压上升率 Rise of off- state voltage	dV/dt	V _{DM} =67% V _{DRM(MAX)} , T _j =125°C, gate open	1000	-	-	V/ μ s	
门极开通时间 Gate controlled turn-on time	tgt	I _{TM} =30A, V _{DM} =V _{DRM(MAX)} , I _G =0.1A, dI _G /dt=5A/ μ S	-	2	-	μ s	

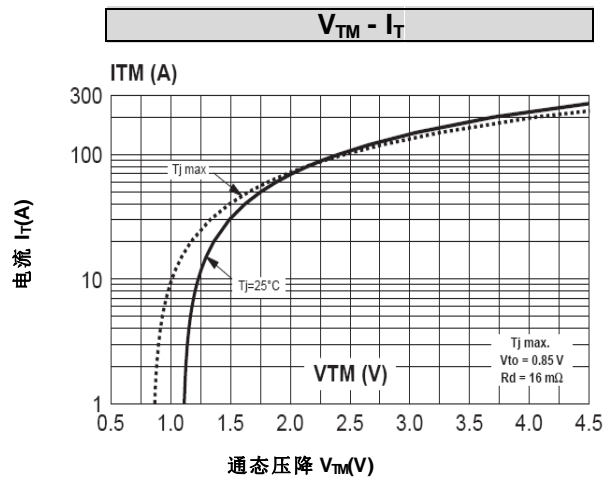
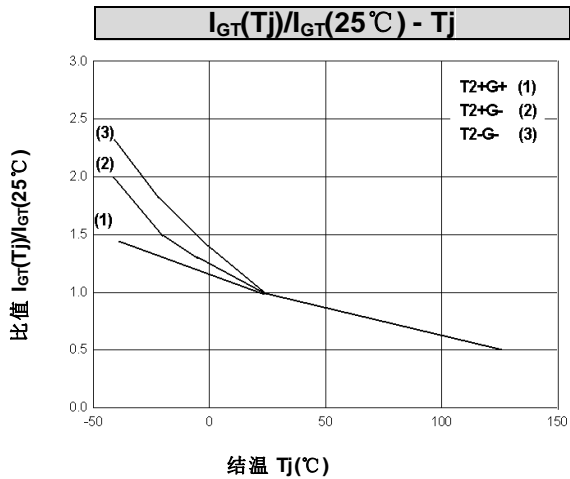
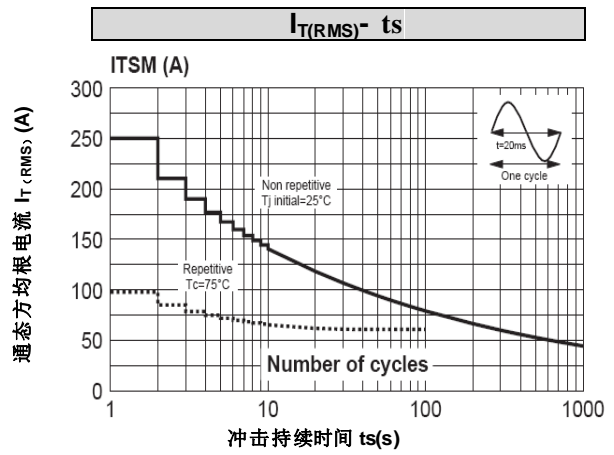
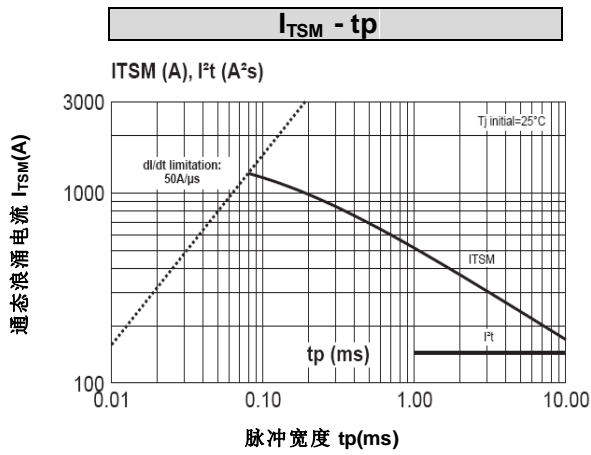
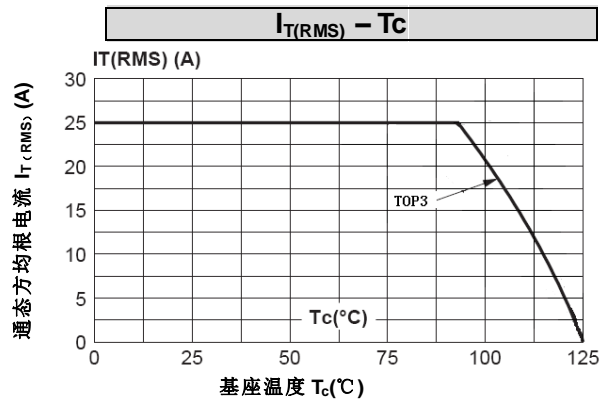
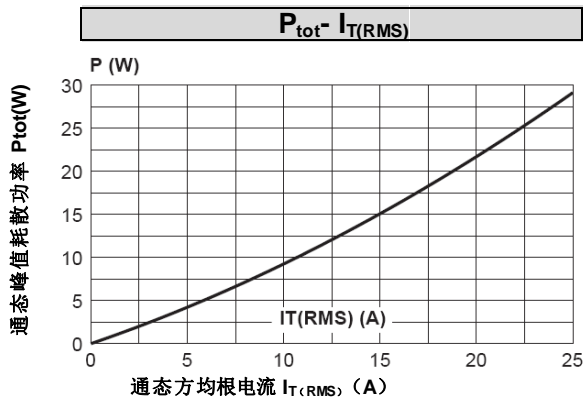
热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	R _{th(j-c)}	full cycle(TOP3)			1.1	°C/W





特征曲线 ELECTRICAL CHARACTERISTICS (curves)

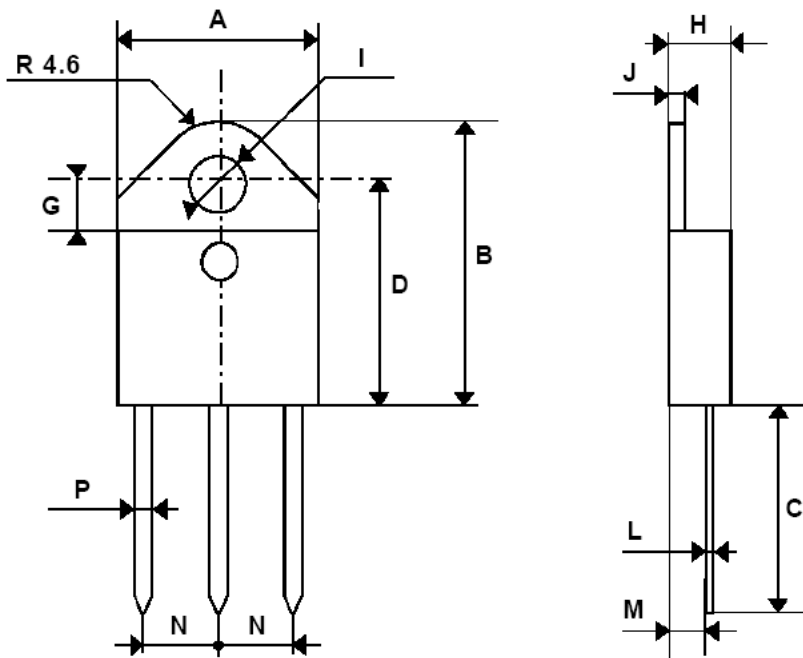




外形尺寸 PACKAGE MECHANICAL DATA

TOP3

单位 Unit : mm



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	15.10	15.50	0.594	0.611
B	20.70	21.10	0.814	0.831
C	14.30	15.60	0.561	0.615
D	16.10	16.50	0.632	0.650
G	3.40	-	0.133	-
H	4.40	4.60	0.173	0.182
I	4.08	4.17	0.161	0.164
J	1.45	1.55	0.057	0.062
L	0.50	0.70	0.019	0.028
M	2.70	2.90	0.106	0.115
N	5.40	5.65	0.212	0.223
P	1.20	1.40	0.047	0.056



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